(Un	JRE STATEMENT	Docket No. 1875-10402		
In Re Application: M	artin et al. DEC 1 9 2	000 H		
Serial No. 10/659,479	Filing Date 9/10/03	Examiner	Group Art Uni	
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OINFORMATION DISCLOSURE CITATION					Applicant(s) Martin et al.					
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	A	5,949,700	9/7/1999	Furuka	wa et al.					
	В	5,973,363	10/26/1999	Staab e	ț al.					
	С	6,069,390	5/30/2000	Hsu et al.						
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Application Number

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